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U.S. DEPARTMENT OF COMMERCE / National Bureau of Standards

NBS* AIDS80: A FORTRAN Program for Crystallographic Data Evaluation

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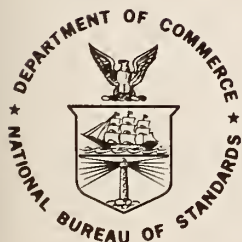
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NBS*AIDS80: A FORTRAN PROGRAM FOR CRYSTALLOGRAPHIC DATA EVALUATION[†]

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Techniques for the computer-assisted evaluation of crystallographic data have been developed to improve the data compilations of the NBS Crystal Data Center and the JCPDS--International Centre for Diffraction Data. The resulting computer program, NBS*AIDS80, can be used for the analysis of unit-cell and powder diffraction data by the general scientific community as well. Research and analysis components include calculation of standard cells and space groups, determination of metric symmetry, checking the data for consistency, generation of d-spacings and indices, and analysis of powder patterns with calculation of figures of merit. Detailed input and output specifications are given.

Key Words: Computer evaluation; crystallographic data analysis; JCPDS--International Centre for Diffraction Data; metric symmetry; NBS Crystal Data Center; powder diffraction; unit cell.

1.0 Introduction

The computer program NBS*AIDS80 is derived from several years of experience at the National Bureau of Standards in the computer-assisted evaluation of crystallographic data. The program or its precursor has been used routinely by the NBS Crystal Data Center for the analysis of crystallographic data in the preparation of Crystal Data Determinative Tables,¹ and it has recently been expanded in collaboration with the JCPDS--International Centre for Diffraction Data for analysis of powder data for the Powder Diffraction File.² The combined evaluation of single-crystal and powder data in a common format enhances the quality of the data in both data compilations.

NBS*AIDS80 was originally intended for use by the data base builders in the evaluation of literature data and the creation of master data files. With such files, research studies can be carried out, indexes can be generated, and publications can be prepared. In addition, the files can be searched in an on-line or batch mode. However, it has become apparent that the data evaluation routines in NBS*AIDS80 are of value as a research and analysis tool for the general scientific community as well. In our evaluation of thousands of entries for the Crystal

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¹ Raised figures indicate literature references on page 24.

Data and Powder Diffraction Files, we have noted an unexpectedly large number of errors in the published crystallographic data, especially with respect to symmetry determination, unit cell transformation, density calculation, and the indexing of powder data. It is our hope that by using NBS*AIDS80 research scientists and journal editors will find and correct such errors prior to publication, and that additional analysis routines will be suggested for incorporation into the program.

2.0 Research and Analysis Applications

NBS*AIDS80 may be used as a research aid in conjunction with routine diffractometry for materials identification and characterization, in addition to the areas mentioned above. For example, in the determination of a crystal structure the program can be used once unit-cell dimensions have been determined to establish the probable symmetry of the lattice, the transformation matrix to the standard setting of the cell and space group, the calculated density for a check on unit cell contents, and the determinative ratios needed to find out if the same or a similar compound previously has been solved. The program should be used again at the end of the structure determination to give final values for publication. NBS*AIDS80 is also valuable in powder diffraction analyses. The program can generate d-spacings for any symmetry and input cell, and input powder data can be indexed based on a known unit cell. Once the pattern has been indexed, the program compares the observed and calculated d-spacings, flags systematic absences if present, and calculates the figures of merit $F(N)$ and $M(20)$. In addition, a table of powder data for publication can be prepared. The research and analysis applications of NBS*AIDS80 are summarized in the following sections.

2.1 Cell and Space Group Transformations

In order to compare unit-cell and space-group data from separate experimental determinations, it is essential that all data be reported in a standard orientation. NBS*AIDS80 transforms the input cell and space group to the Crystal Data setting, and the space-group number is assigned. The Crystal Data cell provides a standard setting for the publication and comparison of unit-cell parameters, and the determinative ratios can be used for direct entry into Crystal Data Determinative Tables for identification of unknowns and location of isostructural materials.

Errors are commonly made in the transformation of unit-cell axes and space groups, especially when unusual centerings are encountered. For example, SbSn and NiO crystallize in a rhombohedrally-distorted sodium chloride structure. These cells are frequently reported using F-centered rhombohedral axes; the corresponding hexagonal axes are calculated ignoring the face-centering, leading to incorrect axes and erroneous indexing of powder data. A more common use of NBS*AIDS80 would be the calculation of hexagonal unit-cell axes from primitive rhombohedral cell parameters.

Perhaps more importantly, it is essential that a given lattice be characterized by the same cell before comparisons are made. De Camp³ has given an excellent example involving a lattice that has two different unit cells which appear to be based on the same three lattice translations. Crystals from two samples of condelphine hydroiodide gave apparently the same triclinic unit-cell dimensions when the cells were reduced using two separate reduction algorithms, with only the angle gamma differing significantly (Figure 1). The other differences were assumed to arise from experimental errors. The two cells are shown to define the same lattice when they are transformed using the NBS*AIDS80 algorithm.

	<u>Cell 1</u>	<u>Cell 2</u>	<u>Cell 1'</u>
a	9.34 ^o Å	9.32 ^o Å	9.34 ^o Å
b	17.39	17.45	17.39
c	9.10	9.09	9.10
α	94.85°	94.84	94.85°
β	119.15	118.83	119.15
γ	88.57	86.50	86.71

Figure 1. Unit cell dimensions for condelphine hydroiodide. Cell 1 is transformed to cell 1' by the matrix (101,010,001).

2.2 Determination of Metric Symmetry

The reduced cell⁴ and the reduced form number are calculated by NBS*AIDS80 to give the metric symmetry of the lattice.⁵ The metric symmetry is the highest symmetry possible for the lattice based solely on geometric considerations. A systematic analysis of the Crystal Data File has shown that the metric symmetry is almost always the same as the true symmetry of the lattice.⁶ The metric symmetry is determined from the Niggli reduced cell by the values of the following vector products⁵ known as the reduced form:

$$\begin{pmatrix} \bar{a} \cdot \bar{a} & \bar{b} \cdot \bar{b} & \bar{c} \cdot \bar{c} \\ \bar{b} \cdot \bar{c} & \bar{a} \cdot \bar{c} & \bar{a} \cdot \bar{b} \end{pmatrix}$$

The reduced form can thus be used to indicate the probable symmetry of the lattice. If the reduced form indicates the possibility of higher symmetry than the input lattice, the program will print the cell with the highest possible lattice symmetry. It is well known that cell reduction provides a practical way to prove that a lattice must be triclinic, as the crystal symmetry can never be higher than the symmetry indicated by the reduced form. The use of the reduced form to indicate probable lattice symmetry is particularly important in light of the current trend towards determining the unit cell of a compound solely from diffractometer data. An example of the use of this procedure is given in Figure 2.

	<u>Initial Cell</u>	<u>Reduced Cell</u>	<u>Metric Cell</u>
a	8.095 ^o Å	8.096 ^o Å	11.698 ^o Å
b	8.096	8.095	25.990
c	30.62	25.990	11.194
α	88.67°	90.00°	90.00
β	58.08	90.00	90.01
γ	87.48	92.52	90.00

$$\begin{pmatrix} 65.5 & 65.5 & 675.5 \\ 0.0 & 0.0 & -2.9 \end{pmatrix} = \begin{pmatrix} a \cdot a & a \cdot a & c \cdot c \\ 0 & 0 & -|a \cdot b| \end{pmatrix}$$

Figure 2. Determination of the metric cell for an unknown antimony tartrate. The metric cell was found by the program to be orthorhombic B-centered, reduced form number 13.

	<u>Cell 1</u>	<u>Cell 2</u>	<u>Cell 3</u>	<u>Common Cell</u>
a	9.407 ^o Å	9.407 ^o Å	9.416 ^o Å	9.407 ^o Å
b	13.773	13.800	13.768	9.407
c	12.829	12.801	12.822	9.416
α	90.06°	90.05°	90.00°	94.06°
β	96.15	95.99	96.14	94.30
γ	89.84	90.01	89.84	94.07

Figure 3. Alternate A-centered cells for chabazite, all leading to a common cell.

It should be emphasized that the reduced form as given by NBS*AIDS80 must be carefully analyzed in order to determine the true metric symmetry, as the assignment of symmetry is often dependent on the assessment of experimental errors. A new routine for symmetry determination is being developed and will be added to the program. This routine will give all possible symmetries and pseudosymmetries. In addition, we plan to add evaluation routines to handle specialized reduced forms that can result from, for example, the mis-indexing of a powder pattern, the determination of the subcell of a lattice, or twinning.

One example of metric pseudosymmetry involves the mineral chabazite, $\text{Ca}_2\text{Al}_4\text{Si}_8\text{O}_{24} \cdot 12\text{H}_2\text{O}$. Chabazite has been reported as having rhombohedral, monoclinic, or triclinic symmetry. Although the metric symmetry is nearly rhombohedral, analysis in our laboratory reveals the symmetry to be monoclinic or lower. Figure 3 gives three similar but distinct A-centered cells that can be related to a common pseudo-rhombohedral cell.⁷

Much of the effort involved in the solution of crystal structures can be avoided if the metric symmetry is determined prior to data collection. In a systematic analysis of organic compounds, we noted a number of cases in which rhombohedral symmetry was incorrectly reported as monoclinic or even triclinic symmetry. While the molecular geometries determined were correct, many more structural parameters than necessary were determined and refined leading to a lower overall accuracy of the structure parameters. Figure 4 gives one such example.

	<u>Input Cell</u>	<u>Rhombohedral Cell (Hexagonal Axes)</u>	<u>Reduced Cell</u>
a	19.900Å	11.489Å	11.489Å
b	11.489		11.489
c	21.258	60.590	21.258
α			74.32°
β	108.18°		74.32
γ			60.00

$$\begin{pmatrix} 132.0 & 132.0 & 451.9 \\ 66.0 & 66.0 & 66.0 \end{pmatrix} = \begin{pmatrix} a \cdot a & a \cdot a & c \cdot c \\ \frac{a \cdot a}{2} & \frac{a \cdot a}{2} & \frac{a \cdot a}{2} \end{pmatrix}$$

Figure 4. Example of a rhombohedral cell reported as a C-centered monoclinic cell. The reduced form (number 9) is clearly rhombohedral.

2.3 Identification of Unknowns

The standard Crystal Data cell and determinative ratios calculated by NBS*AIDS80 can be used for the identification of unknown compounds. For example, the unknown antimony tartrate mentioned above (see Figure 2) was identified using Volume 3 of Crystal Data Determinative Tables. The B-centered orthorhombic cell ($a = 11.694(5)$, $b = 25.961(9)$, $c = 11.192(5)$, $a/b = 0.4504$, $c/b = 0.4311$) was readily identified as potassium antimony tartrate trihydrate using the portion of the Tables given in Figure 5.

	<u>a/b</u>	<u>c/b</u>	<u>a</u>	<u>b</u>	<u>c</u>	<u>Formula</u>
	0.4502	0.3664	8.76	19.43	7.13	C ₁₅ H ₁₀ Cl ₂
	0.4506	0.3361	9.251	20.53	6.901	C ₁₅ H ₂₃ Br
→	0.4510	0.4316	11.696	25.932	11.192	K ₂ Sb ₂ C ₈ H ₄ O ₁₂ ·3H ₂ O
	0.4511	0.4473	8.746	19.388	8.672	CaC ₆ H ₁₂ O ₆ ·3H ₂ O

Figure 5. Identification of an unknown antimony tartrate using Crystal Data Determinative Tables.

Even though the compound is supposedly known, it is always advisable to obtain the standard cell and check for identification prior to data collection. The crystal used for data collection frequently does not correspond to the analysis of the bulk material. For example, data on orthorhombic sulfur has mistakenly been collected many times.

An alternative identification scheme will soon be available using the reduced cells of all materials given in Crystal Data. This Identification File currently exists at NBS, and it will soon be available as part of the NIH-EPA Chemical Information System (CIS).⁸ It will also be issued in a printed format, in which the reduced cell as given by NBS*AIDS80 can be used for identification.

2.4 Checking the Data for Consistency

The program performs a check of the consistency of the unit cell, Z, and formula through a density calculation. The molecular weight is computed based on the input formula, and the cell volume is calculated. Although these computations may seem trivial, our recent experience as editors reveals that the density calculation is incorrectly reported in 15% of the cases. The examples given in Figure 6 are taken from reports of quantitative structure determinations, so there should be no questions about the unit cell contents. The discrepancies often arise owing to calculation of the density using preliminary cell dimensions or unit cell contents. Other sources of error include incorrect computation of molecular weight, cell volume, and Z or an approximate (or missing) value for Avogadro's number.

<u>Formula</u>	<u>Measured Density</u>	<u>Calculated Density</u>	<u>NBS*AIDS80 Density</u>
Cd ₂ P ₂ O ₇	4.90	5.04	4.886
Ba ₃ P ₂	4.1	4.52	3.371
GeLi ₂ Zn	4.035	4.15	4.353
Mn ₃ (PO ₄) ₂	4.1	3.92	3.798

Figure 6. Comparison of measured and calculated densities reported in the literature with densities calculated by NBS*AIDS80.

2.5 Powder Pattern Analysis

The program can be used to generate 2 θ and d-spacings based on input-cell and space-group information for any crystal system. This feature was derived from the program "Lattice Parameter Least Squares Refinement"⁹ with minor modifications. If reflection data are input (2 θ , d, sin θ / λ , or Q) without hkl's assigned to any or all of the reflections, NBS*AIDS80 will assign the indices of the nearest reflection provided that $|\Delta(2\theta)| < 0.5^\circ$. A small segment of the computer printout from the hkl/d-generation and indexing segment is shown in Figure 7. The "C" following each observed d-spacing (D OBS) indicates that the computer code has assigned the indices. If proper hkl's were given as input this column would be blank. However, if a given hkl is

not allowed in the input space group the column would contain an "N". Unindexable lines are marked with a "U". The maximum 2θ value for hkl/d -generation is an input parameter or, if left blank, determined by the range of input lines. The extinction conditions are generated automatically from the aspect symbol, space group symbol, or cell centering symbol. They may optionally be entered as input data as well.

Following the hkl , d and 2θ table, a pattern summary is printed as shown in Figure 8. Included are the number of lines possible out to 2θ max, the number of lines resolvable based on an estimated resolution factor, and the number of lines observed. This summary expresses the coverage of the experimental measurements. Next is a tabulation of the number of lines input, number indexed and number remaining unindexed. For the indexed lines the average and maximum magnitude of $\Delta(2\theta)$ are given. An average $|\Delta(2\theta)|$ of $<0.02^\circ$ should be expected for high quality data. Data of this quality, or better, have been reported for nearly two decades primarily due to the use of internal 2θ standards. Another assessment of the fit between the observed and calculated 2θ 's is the number of lines with $|\Delta(2\theta)|$ greater than some arbitrary limit. The JCPDS--International Centre for Diffraction Data currently uses a limit of 0.05° for "★" quality patterns and a limit of 0.20° for "I" quality patterns. (However, for a PDF card to be assigned either of these quality marks, chemical and intensity data criteria must also be satisfied.)

Two other assessments of the fit of the input cell and observed pattern are calculated by the program. $M(20)$ is an indication of the correctness of the unit cell. According to de Wolff¹⁰ a value of $M(20) > 10$ coupled with two or fewer unindexed lines indicates that the cell is substantially correct. A value of $M(20) < 5$ and/or several unindexed lines strongly suggests that the cell is not appropriate. The Smith-Snyder figure of merit $F(N)$ ¹¹ assesses the overall fit of the experimental data and cell as well as the coverage or completeness of the observations. For every one of the 105 patterns reported in Monograph 25, Section 16 and Section 17,¹² $M(20)$ exceeded 15 and $F(30)$ exceeded 13. However, in evaluating data in the literature, we often find indexed lines with $|\Delta(2\theta)| > 0.5^\circ$, and patterns with $M(20) < 5$ and $F(30) < 5$. Often the reasons for the low quality of fit cannot be explained. However sometimes large discrepancies are typographical in origin. NBS*AIDS80 has a $d/I/hkl/2\theta$ table generation subroutine to help eliminate these errors (Figure 9). The subroutine determines the appropriate number of significant digits for each d -value based on the average magnitude of error in 2θ for the entire pattern. This keeps the round-off errors due to formatting of d -values less than the average magnitude of the error in 2θ .

MESSAGEPOWDER PATTERN GENERATION/ANALYSIS FOR SYSTEM TET

2-THETA(MAX) = 100.23

D(MIN) = 1.003868

2 CONDITIONS FOR NON-EXTINCTION CALLED FOR

CLASS CONDITION(S)

HKL H+K+L = 2N

HHL 2H+L = 4N

N	D CALC	D OBS	INT	AUTHORS H K L	PROGRAM H K L	OBS 2-THETA	CALC 2-THETA	DIFF 2-THETA
1	5.4508				1 0 1		16.248	
**	5.4508	5.4502C	80	1 0 1		16.250	16.248	-.002
2	3.8489				2 0 0		23.090	
**	3.8489	3.8472C	65	2 0 0		23.100	23.090	-.010
3	3.1485				1 1 2		28.323	
4	3.1441				2 1 1		28.364	
**	3.1441	3.1434C	100	2 1 1		28.370	28.364	-.006
5	2.7254				2 0 2		32.836	
**	2.7254	2.7250C	15	2 0 2		32.840	32.836	-.004
6	2.7216				2 2 0		32.883	
**	2.7216	2.7194C	20	2 2 0		32.910	32.883	-.027

Figure 7. A segment of the hkl/d-generation output of NBS*AIDS80 for $\text{NH}_4\text{H}_2\text{AsO}_4$.

REFLECTION SUMMARY FOR ENTIRE PATTERN:

ESTIMATED RESOLUTION = .075 DEG. 2-THETA

THEORETICAL LINES TOTAL = 75

THEORETICAL RESOLVABLE = 47

UNIQUE OBSERVED LINES = 39

TOTAL LINES INPUT = 39

NUMBER INDEXED = 39

NUMBER UNINDEXED = 0

*****FOR INDEXED LINES*****

AVERAGE 2-THETA DIFFERENCE = .012

MAXIMUM 2-THETA DIFFERENCE = .030

WITH DIFF>0.05 (STAR LIMIT) = 0

WITH DIFF>0.20 (I LIMIT) = 0

M(20) = 59.49 (DLIMIT = 1.3589, # POSSIBLE = 33)

F(30) = 47.69 (DELTA 2 THETA = .0123, # POSSIBLE = 51)

Figure 8. Pattern summary for $\text{NH}_4\text{H}_2\text{AsO}_4$.

5.450	80	1	0	1	16.25
3.847	65	2	0	0	23.10
3.143	100	2	1	1	28.37
2.725	15	2	0	2	32.84
2.719	20	2	2	0	32.91
2.438	4	1	0	3	36.83
2.433	4	3	1	0	36.92
2.058	45	3	2	1	43.96
1.9291	1	0	0	4	47.07
1.9241	3	4	0	0	47.20
1.8166	9	3	0	3	50.18

Figure 9: $d/I/hk\ell/2\theta$ Table Generation for $\text{NH}_4\text{H}_2\text{AsO}_4$.

3.0 Input Information

Any number of cells or powder patterns may be processed in a given run. The input consists of a single CONTROL CARD followed by one or more sets of DATA CARDS. All data sets in a given run will be processed as a homogeneous group as indicated by the control card. A typical input deck thus consists of one control card followed by data set 1, data set 2, etc. Examples of input decks and output listings are given in Appendix C.

The following card types may be input for each data set:

CARD 1	Cell parameters and crystal system (always required)
CARD 2	Cell parameter standard deviations (optional)
CARD 3	Space group, Z, Dm, Dx (required)
CARD 6	Compound name (optional)
CARD 7	Chemical formula (optional)
CARD 8	Empirical formula (optional, but necessary for full analysis)
CARD B	Comments (optional)
CARD F	Pattern information (1) (required if powder data is input)
CARD G	Pattern information (2) (optional if powder data is input)
CARD H	Extinction conditions (optional)
CARD I	Powder pattern (required for powder data input)
CARD K	Entry termination (always required)

Each set of data cards must begin with CARD 1 and must end with CARD K. In addition, CARD F and CARD I are required for powder data analysis. The card types are indicated in column 80 and each data set must have the cards ordered in the above sequence. The following table gives the card types required for typical analyses:

<u>Program analysis functions</u>	<u>Cards required</u>
Cell analysis (reduced cell, Crystal Data cell, and metric symmetry determination)	1, 3, K
Cell analysis, density, molecular weight	1, 3, 7 <u>or</u> 8, K
Cell analysis, powder pattern analysis	1, 3, F, I, K
Cell analysis, density, molecular weight, powder pattern analysis	1, 3, 7 <u>or</u> 8, F, I, K
Generation of d-spacings, cell analysis	1, 3, F, K

CONTROL CARD (processing codes)

<u>Column</u>	<u>Format</u>	<u>Item</u>
5	I1	IJØB - type of run 0 = data analysis (cell or cell and powder pattern) 2 = d-spacing generation (no input powder data)
35	I1	MØN25 - key for printing table of powder data in the format of NBS Monograph 25 0 = no output 1 = print
46-50	I5	ITHMX - 2ø limit for d-spacing generation (if IJØB = 2) given as an integer, right justified
55	I1	ICØL - print control Blank = 120 columns or greater 1 = 80 column printing

CARD 1 CELL PARAMETERS

Column	Format	Item
1-9	F9.5	a (original data) in Å
10-18	F9.5	b
19-27	F9.5	c
28-35	F8.3	α (original data) in degrees
36-43	F8.3	β
44-51	F8.3	γ
73-78	6A1	Reference code, alphanumeric (ID for data set)
79	A1	Crystal system code A = anorthic (triclinic) H = hexagonal M = monoclinic R = rhombohedral Ø = orthorhombic (H or R axes) T = tetragonal C = cubic
80	A1	1 (card type 1)

Note: Important: To prevent program malfunction, enter only those cell parameters required to define the cell:

anorthic (triclinic)	a, b, c, α , β , γ
monoclinic (a-unique)	a, b, c, α
monoclinic (b-unique)	a, b, c β
monoclinic (c-unique)	a, b, c γ
orthorhombic	a, b, c
tetragonal	a c
hexagonal	a c
rhombohedral (H axes)	a c
rhombohedral (R axes)	a α
cubic	a

For the rhombohedral crystal system, it is necessary to use the crystal system code "R" (even when the input cell is based on hexagonal axes) in order to obtain the correct reduced cell and metric symmetry analysis.

CARD 2 CELL PARAMETER STANDARD DEVIATIONS (optional)

<u>Column</u>	<u>Format</u>	<u>Item</u>
1-9	F9.5	$\sigma(a)$
10-18	F9.5	$\sigma(b)$
19-27	F9.5	$\sigma(c)$
28-35	F8.3	$\sigma(\alpha)$
36-43	F8.3	$\sigma(\beta)$
44-51	F8.3	$\sigma(\gamma)$
80	A1	2 (card type 2)

CARD 3 SPACE GROUP, Z, DENSITY

Column	Format	Item
1-8	8A1	Space group, aspect in Laue class, or cell centering (left justified)
20-25	F6.0	Z (may be entered as an integer, right justified, or as a decimal number)
30-35	F6.3	Dm (measured density)
38-43	F6.3	Dx (calculated density)
80	A1	3 (card type 3)

Note: Enter the space group or aspect, left justified. The symbols may be in upper and lower case, or all upper case.

$P2_1/c \rightarrow P21/C$ (or $P21/c$) $R\bar{3}m \rightarrow R-3M$ (or $R-3m$)

$P4_32_12 \rightarrow P43212$ $I^*/\ast \rightarrow I^*/\ast$

If only the cell centering is known, enter the appropriate symbol (P, C, F, etc.) in column 1 under space group. If no centering is indicated, a primitive cell is assumed. The following symbols may be input:

anorthic (triclinic)	P, A, B, C, F, I
monoclinic	P, A, B, C, F, I
orthorhombic	P, A, B, C, F, I
tetragonal	P, C, F, I
hexagonal	P
rhombohedral (H axes)	R
rhombohedral (R axes)	R, F, I
cubic	P, F, I

CARD 6 COMPOUND NAME (optional)

Column	Format	Item
1-67	67A1	Compound name (left justified)
80	A1	6 (card type 6)

CARD 7 CHEMICAL FORMULA (optional)

<u>Column</u>	<u>Format</u>	<u>Item</u>
1-67	67A1	Chemical formula (left justified)
80	A1	7 (card type 7)

Note: If the chemical formula is input using the conventions specified below, the program will calculate the empirical formula and Card 8 is not required. The formula must be consistent with Z.

The formula is expressed as a sequence of discrete units. Each unit ends with a space. The following symbols are allowed:

1. Chemical element and number. Each element is followed by the number of atoms of that element; the element-number unit is terminated by a space. If the number of atoms of a given element is 1, then the 1 may be omitted. The element symbols may be in upper and lower case, or all upper case. Decimal multipliers are allowed.

Ba Cl₂ (or BA CL2) Na₂ S O₄ (or NA2 S O4)

Bi_{0.5} Ca_{0.5} Sr O₃ (or BIO.5 CAO.5 SR O3)

2. Parentheses. A left parenthesis is always preceded and followed by a blank. A right parenthesis is always preceded by a blank and may be followed by a multiplier.

Al₂ (S O₄)₃ Co (C O)₆ (N H₄)₂ S O₄

3. Brackets. These are treated the same as parentheses.

Ni₃ [Co (C N)₆]₂

Mg₃ [B (O H)₄]₂ F (O H) S O₄

4. Exclamation point. This symbol is used to indicate a center dot. It may be followed by a multiplier.

Rb₂ Zn (Be F₄)₂ !₆ H₂ O

2 (N H₄)₂ S O₄ ! H₂ O

La P O₄ !_{0.5} H₂ O

CARD 8 EMPIRICAL FORMULA (optional; not needed if Card 7 is input)

<u>Column</u>	<u>Format</u>	<u>Item</u>
1-67	67A1	Empirical formula (left justified)
80	A1	8 (card type 8)

Note: The empirical formula must be consistent with Z.

Follow each element symbol with a multiplier, and separate each element-multiplier unit with a space. A multiplier of 1 may be omitted.

Ca3 H2 Mg 024 Si C22 H36 Cl

The element symbols may be in upper and lower case, or all upper case; the first element symbol must begin in column 1.

CARD B COMMENTS (optional)

<u>Column</u>	<u>Format</u>	<u>Item</u>
1-67	67A1	Any alphanumeric comments
80	A1	B (card type B)

CARD F PATTERN INFORMATION (1) (required only if powder data input or if d-generation is requested)

<u>Column</u>	<u>Format</u>	<u>Item</u>
7-15	F9.5	Wavelength in Å (Blank = 1.5405)
30	A1	Code for original data Blank = no data to be read (calculate hkl's and d's) 1 = θ 2 = 2θ D = d-spacings S = $\sin^2\theta$ Q = $(d^*)^2 = 1/d^2$
80	A1	F (card type F)

CARD G PATTERN INFORMATION (2) (optional if powder data input)

<u>Column</u>	<u>Format</u>	<u>Item</u>
17-20	F4.2	2 θ tolerance used in marking poor fit between observed and calculated 2 θ 's (Blank = 0.05)
22	A1	Rhombohedral \rightarrow hexagonal transformation code for hkl's Blank = normal (no transformation) R = input hkl's, based on rhombohedral axes, are to be transformed to hkl's based on hexagonal axes
80	A1	G (card type G)

CARD H EXTINCTION CONDITIONS (optional if powder data input or generated)

Column	Format	Item
21-47	27I1	Extinction codes (see note)
80	A1	H (card type H)

Note: Extinction conditions will automatically be read from the extinction file for all space group and aspect settings given in Appendix A. Conditions must be input on this card for unusual orientations (e.g., c-unique monoclinic) or if the extinction file is not assigned.

If rhombohedral hkl 's are to be transformed to hexagonal hkl 's (column 22 on Card G = "R"), always input the special conditions for the rhombohedral cell based on hexagonal axes. The general rhombohedral condition ($-h+k+l=3n$) need not be input.

See International Tables for X-ray Crystallography,⁵ Volume 1, for the necessary extinctions for each space group. For each extinction, enter the integer value for "B" from the following table in the appropriate column:

Indices	Condition	Column	Indices	Condition	Column
hkl	$h+k=Bn$	21	$h0l$	$h=Bn$	34
hkl	$h+l=Bn$	22	$h0l$	$l=Bn$	35
hkl	$k+l=Bn$	23	$h0l$	$h+l=Bn$	36
hkl	$h+k=Bx,$ $h+l=By,$ $k+l=Bz$	24	$hk0$	$h=Bn$	37
hkl	$h+k+l=Bn$	25	$hk0$	$k=Bn$	38
hkl	$-h+k+l=Bn$	26	$hk0$	$h+k=Bn$	39
$hh\ell$	$h=Bn$	27	$hh0$	$h=Bn$	40
$hh\ell$	$\ell=Bn$	28	$h00$	$h=Bn$	41
$hh\ell$	$h+l=Bn$	29	$0k0$	$k=Bn$	42
$hh\ell$	$2h+l=Bn$	30	00ℓ	$\ell=Bn$	43
$Ok\ell$	$k=Bn$	31	$h\ell\ell$	$h=Bn$	44
$Ok\ell$	$\ell=Bn$	32	$h\ell\ell$	$\ell=Bn$	45
$Ok\ell$	$k+l=Bn$	33	$h\ell\ell$	$h+l=Bn$	46
			$h\ell\ell$	$h+2\ell=Bn$	47

CARD I POWDER PATTERN (required only if powder data input)

Note: The data can be entered with either one, two, or three lines per card, in increasing 2θ (decreasing d). Up to 200 lines may be entered for a given powder pattern; repeat Card I as necessary.

<u>Column</u>	<u>Format</u>	<u>Item</u>
1-7	F7.n	θ , 2θ , d , $\sin^2\theta$, or Q for line 1 (Data must agree with the data type indicated in column 30 of Card F. Give as many significant figures as possible.)
8-10	I3	Relative intensity (any scale)
12-14	I3	h
15-17	I3	k
18-20	I3	l
24-30	F7.n	θ , 2θ , d , $\sin^2\theta$, or Q for line 2
31-33	I3	Relative intensity
35-37	I3	h
38-40	I3	k
41-43	I3	l
47-53	F7.n	θ , 2θ , d , $\sin^2\theta$, or Q for line 3
54-56	I3	Relative intensity
58-60	I3	h
61-63	I3	k
64-66	I3	l
80	A1	I (card type I)

CARD K ENTRY TERMINATION

<u>Column</u>	<u>Format</u>	<u>Item</u>
80	A1	K (card type K)

4.0 Output Information

Part 1. Warning and Error Messages

A warning message (**WARNING**) is printed if unusual data are entered. A warning is also given if the observed and calculated densities do not agree, if input hkl indices are not consistent with space group extinctions, or if the figure of merit indicates that the cell used in indexing a powder pattern is suspect. If the analysis of the reduced form indicates that a higher metric symmetry exists than was input, a warning message is printed and the cell parameters for the higher-symmetry cell are given along with the matrix for transformation of the initial cell to the higher-symmetry cell.

An error message (**ERROR**) usually indicates that an illegal parameter has been input or that the program has failed at some point. The input cards should be checked for accuracy.

A message (**MESSAGE**) relays information only, and does not indicate a warning or an error.

Part 2. Cell Analysis

The input data and derived parameters are printed as a series of card images, with the type of data output summarized. Some or all of the following card images may be output:

CELL Initial cell, as input.

ESDS Standard deviations in the initial cell, if input; average standard deviation in axial lengths in parts per 10^5 ; and quality index code. An "E" following the average standard deviation indicates that the program has assumed a value of 5 in the least significant digits.

<u>Average standard deviation (parts per 10^5)</u>	<u>QI code</u>
0 - 1	A
2 - 5	A-
6 - 10	B
11 - 50	B- (typical single-crystal diffractometer)
51 - 100	C
101 - 500	C-
501 - 1000	D
1001 - 5000	D-
5001 - 9999	F

SG-1 Space group as input; space group or aspect number (see Appendix A); Z, Dm, and Dx as input; initial cell volume.

SG-2 Space group for Crystal Data cell; space group number; Z for Crystal Data cell; Dx calculated by the program; molecular weight; volume of Crystal Data cell. If no Z is input, then a value of 1 is assumed in the calculation of Dx; Dx is then followed by a "G".

NAME Compound name as input.

CHEM Chemical formula as input.

EMPR Empirical formula as input or as calculated from the chemical formula.

COMM Comments as input.

MATX Transformation matrices:
 Initial cell to reduced cell (T-2)
 Determinant and initial cell to Crystal Data cell
 Inverse of initial cell to Crystal Data cell, if not identity matrix.

C-IN Initial cell and cell volume, as interpreted by the program.

C-RD Reduced cell, reduced cell volume, and reduced form number (see Appendix B). An "X" following the reduced form number indicates that the metric symmetry exceeds the input crystal symmetry.

C-CD Crystal Data cell and determinative ratios. For the conventions used to define the Crystal Data cell see the Introduction to Volume 3 or 4 of Crystal Data Determinative Tables.¹ The first determinative ratio is $\frac{a}{b}$ for anorthic, monoclinic, and orthorhombic; $\frac{c}{a}$ for tetragonal, hexagonal, and rhombohedral (hexagonal axes); and $\frac{a}{b}$ for cubic. The second determinative ratio is $\frac{c}{b}$ for anorthic, monoclinic, and orthorhombic.

E-CD Standard deviations of the Crystal Data cell parameters, if initial standard deviations were input.

DOTM Dot product matrix ($\hat{a} \cdot \hat{a}$, $\hat{b} \cdot \hat{b}$, $\hat{c} \cdot \hat{c}$, $\hat{b} \cdot \hat{c}$, $\hat{a} \cdot \hat{c}$, $\hat{a} \cdot \hat{b}$) of the reduced cell. The values given for the dot products should be compared with the data in Appendix B to determine metric symmetry.

PDF1 Pattern information (1) as input (card F).

PDF2 Pattern information (2) as input (card G).

EXTC Extinction conditions as input (card H).

HIST Date processed; number of warnings generated; number of errors generated; year-version of NBS*AIDS80.

Part 3. Powder Pattern Analysis

The data are sorted on increasing 2θ , and intensities are rescaled to $I(\max) = 100$. Observed and calculated d-spacings, 2θ 's and hkl 's are given, as well as $\Delta(2\theta)$ for indexed lines. Any line that is unindexed on input will be assigned the indices of the closest calculated line provided that the observed and calculated 2θ 's agree within 0.5° . The following editorial marks may be assigned to a given line by the program:

C = hkl assigned by the program

U = unindexed

N = not permitted by the space group

The reflections exceeding the $|\Delta(2\theta)|$ tolerance are listed. A reflection summary is given for the entire pattern, including the following: the theoretical number of lines possible, the number of lines resolvable, the number of unique observed lines, the total number of lines input, and the number of lines indexed and unindexed. For the indexed lines, the average and maximum $|\Delta(2\theta)|$ are given, along with the number of lines exceeding the tolerance of the PDF "★" limit ($|\Delta(2\theta)| \leq 0.05^\circ$) and "I" limit ($|\Delta(2\theta)| \leq 0.20^\circ$).

The figures of merit $M(N)$ and $F(N)$ proposed by de Wolff¹⁰ and by Smith and Snyder,¹¹ respectively, are calculated for indexed powder patterns. Unindexed lines are not included in the calculation of either figure of merit. $M(N)$ is defined by the equation

$$M(N) = \frac{Q(N)}{2\langle|\Delta Q|\rangle N}$$

where N is 20 or the number of indexed lines input if less than 20, $Q(N)$ is the Q -value ($= 1/d^2$) of the N^{th} line, and $\langle|\Delta Q|\rangle$ is the average magnitude of the difference between $Q(\text{obs})$ and $Q(\text{calc})$. According to de Wolff, a value of $M(20) > 10$ will indicate the essential correctness of the indexing provided that there are not more than two unindexed lines with $2\theta < 2\theta(N)$. The Smith-Snyder figure of merit is defined by

$$F(N) = \frac{1}{\langle|\Delta 2\theta|\rangle} \frac{N}{N(\text{poss})}$$

where N is 30 or the number of indexed lines input if less than 30, and $N(\text{poss})$ is the number of theoretical lines possible (excluding space-group extinct lines) up to and including the N^{th} observed and indexed line. Co-positional lines (e.g. cubic indices 221 and 300) are counted as one possible line. The recommended format for reporting this figure of merit is $F(N) [\langle|\Delta 2\theta|\rangle, N(\text{poss})]$. The factor $N/N(\text{poss})$ is a

measure of the completeness of the measurements while $\langle |\Delta 2\theta| \rangle$ indicates the consistency of the unit cell with the experimental 2θ values. For both M(N) and F(N) the average error values are based on the assigned hkl 's. If a line is input with multiple indices, then all possible differences (obs - calc) for that line are used in calculating the average error value.

Part 4. Table of Powder Data for Publication

A table of d-spacings, intensities, hkl indices, and 2θ 's is prepared if MØN25 = 1 on the control card. The number of significant figures given for the spacings is determined by the overall $|\Delta(2\theta)|$ for the pattern.

5.0 Program Details

Examples of input card decks and output listings for typical data analysis runs are given in Appendix C. NBS*AIDS80 is written in FORTRAN and is currently running on a UNIVAC 1100 series computer. As overlaid, it occupies about 21K words of memory and requires from one second for cell analysis to five seconds for cell and powder data analysis. To improve portability of the program, we have grouped all ENCODE and DECODE statements together in a single subroutine. Laboratories with compilers that do not handle ENCODE and DECODE statements may have to write assembly language subroutines. The program makes use of the full 128 character ASCII character set. However, input may be restricted to only upper case for formulas and space group symbols. The program will be provided free of charge provided that a new, unlabeled 9 track magnetic tape, certified to 1600 bpi, accompanies the request. The supplied tape will be written unblocked in ASCII at 1600 bpi.

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APPENDIX A

SPACE GROUPS AND ASPECTS

The following tables give the space groups and diffraction aspects allowed by NBS*AIDS80 for the assignment of space group and aspect numbers and for the generation of systematic absences. Although any valid space group or diffraction aspect may be entered on Card 3, only those listed in these tables (in addition to cell centering symbols) will result in the automatic generation of systematic absences. For the monoclinic system the b-axis is assumed to be unique.

Part I (Space Groups)

The space group numbers assigned by the program correspond to those given in the International Tables for X-ray Crystallography.⁵ The assigned number is followed by an orientation code when more than one orientation is permitted for a given space group. In the monoclinic system these codes are A, B, or C, and in the orthorhombic system they are A, B, C, D, E, or F.

Part II (Aspects)

The diffraction aspect, if known, should be entered on Card 3 when the space group is not uniquely defined. The diffraction aspects for each Laue class have been given by Donnay and Kennard¹³ and are reprinted in Supplement II of the 3rd Edition of Crystal Data Determinative Tables,¹ Volumes 1 and 2. The four aspects that begin with the Laue group symmetry should be rewritten so that the lattice type appears first, followed by the Laue group:

$$\overline{1}P^* \rightarrow P^*, -1$$

$$\overline{3}P^* \rightarrow P^*, -3$$

$$\overline{3}mP^*c1 \rightarrow P^*c1, -3m$$

$$\overline{3}mP^*1c \rightarrow P^*1c, -3m$$

An aspect number assigned by the program is preceded by an asterisk(*), and this number corresponds to the number of the highest symmetry space group that is consistent with the diffraction aspect. The aspects for the enantiomorphic space groups (e.g. $P4_12_12$ and $P4_32_12$) are assigned the number corresponding to the lower-numbered space group of the pair. The orientation codes for the monoclinic and orthorhombic systems are the same as those assigned to the space groups.

PART I
SPACE GROUPS

Anorthic (Triclinic) System

Space Group No.	Aspect No.	Space Group Symbols
1	2	P1
2	2	P $\bar{1}$

Monoclinic System

Space Group No.	Aspect No.	A*	B	C
3	10	P2		
4	11	P2 ₁		
5	12	C2	A2	I2
6	10	Pm		
7	13	Pc	Pa	Pn
8	12	Cm	Am	Im
9	15	Cc	Aa	Ia
10	10	P2/m		
11	11	P2 ₁ /m		
12	12	C2/m	A2/m	I2/m
13	13	P2/c	P2/a	P2/n
14		P2 ₁ /c	P2 ₁ /a	P2 ₁ /n
15	15	C2/c	A2/a	I2/a

* Orientation code

Orthorhombic System

Space Group No.	Aspect No.	Space Group Symbols					
		A	B	C	D	E	F
16	47	P222					
17		P222 ₁	P2 ₁ 22	P22 ₁ 2			
18		P2 ₁ 2 ₁ 2	P22 ₁ 2 ₁	P2 ₁ 22 ₁			
19		P2 ₁ 2 ₁ 2 ₁					
20		C222 ₁	A2 ₁ 22	B22 ₁ 2			
21	65	C222	B222	A222			
22	69	F222					
23	71	I222					
24	71	I2 ₁ 2 ₁ 2 ₁					
25	47	Pmm2	Pm2m	P2mm			
26	51	Pmc2 ₁	P2 ₁ ma	P2 ₁ am	Pb2 ₁ m	Pcm2 ₁	Pm2 ₁ b
27	49	Pcc2	Pb2b	P2aa			
28	51	Pma2	P2cm	P2mb	Pbm2	Pc2m	Pm2a
29	57	Pca2 ₁	P2 ₁ ca	Pb2 ₁ a	P2 ₁ ab	Pc2 ₁ b	Pbc2 ₁
30	53	Pnc2	Pcn2	Pn2b	Pb2n	P2na	P2an
31	59	Pmn2 ₁	Pnm2 ₁	P2 ₁ nm	Pn2 ₁ m	Pm2 ₁ n	P2 ₁ mn
32	55	Pba2	P2cb	Pc2a			
33	62	Pna2 ₁	Pbn2 ₁	P2 ₁ cn	P2 ₁ nb	Pn2 ₁ a	Pc2 ₁ n
34	58	Pnn2	Pn2n	P2nn			
35	65	Cmm2	Bm2m	A2mm			
36	63	Cmc2 ₁	A2 ₁ am	A2 ₁ ma	Bm2 ₁ b	Bb2 ₁ m	Ccm2 ₁
37	66	Ccc2	A2aa	Bb2b			
38	65	Amm2	Am2m	B2mm	C2mm	Bmm2	Cm2m

Orthorhombic System (cont.)

Space Group No.	Aspect No.	Space Group Symbols					
		A	B	C	D	E	F
39	67	Abm2	Bma2	C2ma	Ab2m	Cm2a	B2am
40	63	Ama2	C2cm	Bbm2	B2mb	Cc2m	Am2a
41	64	Aba2	Ab2a	C2ca	B2ab	Cc2a	Bba2
42	69	Fmm2	Fm2m	F2mm			
43		Fdd2	Fd2d	F2dd			
44	71	Imm2	Im2m	I2mm			
45	72	Iba2	Ib2a	I2aa			
46	74	Ima2	Im2a	Ibm2	I2am	Ib2m	I2ma
47	47	Pmmm					
48		Pnnn					
49	49	Pccm	Pmaa	Pbmb			
50		Pban	Pncb	Pcna			
51	51	Pmma	Pmcm	Pcmm	Pmam	Pbmm	Pmmb
52		Pnna	Pnnb	Pnan	Pncn	Pbnn	Pcnn
53	53	Pmna	Pncm	Pbm n	Pman	Pcnm	Pnmb
54		Pcca	Pbaa	Pbcb	Pccb	Pbab	Pcaa
55	55	Pbam	Pcma	Pmcb			
56		Pccn	Pbnb	Pnaa			
57	57	Pbcm	Pcmb	Pbma	Pcam	Pmab	Pmca
58	58	Pnnm	Pnmn	Pmnn			
59	59	Pmmn	Pnmm	Pmnm			
60		Pbcn	Pnab	Pnca	Pbna	Pcan	Pcnb
61		Pbca	Pcab				

Orthorhombic System (cont.)

Space Group No.	Aspect No.	Space Group Symbols					
		A	B	C	D	E	F
62	62	Pnma	Pmnb	Pbnm	Pmcn	Pcmn	Pnam
63	63	Cmcm	Bbmm	Amam	Amma	Cmmm	Bmbb
64	64	Cmca	Abam	Ccma	Abma	Bmab	Bbam
65	65	Cmmm	Bmmm	Ammm			
66	66	Cccm	Amaa	Bbmb			
67	67	Cmma	Abmm	Bmam			
68		Ccca	Bbab	Abaa			
69	69	Fmmm					
70		Fddd					
71	71	Immm					
72	72	Ibam	Imaa	Ibma			
73		Ibca					
74	74	Imma	Ibmm	Imam			

Tetragonal System

Space Group No.	Aspect No.	Space Group Symbols	Space Group No.	Aspect No.	Space Group Symbols
75	83	P4	76	76	P4 ₁
77	84	P4 ₂	78	76	P4 ₃
79	87	I4	80		I4 ₁
81	83	P4̄	82	87	I4̄
83	83	P4/m	84	84	P4 ₂ /m
85		P4/n	86		P4 ₂ /n
87	87	I4/m	88		I4 ₁ /a

Tetragonal System (cont.)

<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>	<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>
89	123	P422	90	113	P4 ₂ 12
91	91	P4 ₁ 22	92	92	P4 ₁ 2 ₁ 2
93		P4 ₂ 22	94		P4 ₂ 2 ₁ 2
95	91	P4 ₃ 22	96	92	P4 ₃ 2 ₁ 2
97	139	I422	98		I4 ₁ 22
99	123	P4mm	100	127	P4bm
101	132	P4 ₂ cm	102	136	P4 ₂ nm
103	124	P4cc	104	128	P4nc
105	131	P4 ₂ mc	106	135	P4 ₂ bc
107	139	I4mm	108	140	I4cm
109	122	I4 ₁ md	110		I4 ₁ cd
111	123	P $\overline{4}$ 2m	112	131	P $\overline{4}$ 2c
113	113	P $\overline{4}$ 2 ₁ m	114		P $\overline{4}$ 2 ₁ c
115	123	P $\overline{4}$ m2	116	132	P $\overline{4}$ c2
117	127	P $\overline{4}$ b2	118	136	P $\overline{4}$ n2
119	139	I $\overline{4}$ m2	120	140	I $\overline{4}$ c2
121	139	I $\overline{4}$ 2m	122	122	I $\overline{4}$ 2d
123	123	P4/mmm	124	124	P4/mcc
125		P4/nbm	126		P4/nnc
127	127	P4/mbm	128	128	P4/mnc
129		P4/nmm	130		P4/ncc
131	131	P4 ₂ /mmc	132	132	P4 ₂ /mcm
133		P4 ₂ /nbc	134		P4 ₂ /nnm

Tetragonal System (cont.)

<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>	<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>
135	135	$P4_2/mbc$	136	136	$P4_2/mnm$
137		$P4_2/nmc$	138		$P4_2/ncm$
139	139	$I4/mmm$	140	140	$I4/mcm$
141		$I4_1/amd$	142		$I4_1/acd$

Hexagonal and Rhombohedral System

<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>	<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>
143	147	$P3$	144	144	$P3_1$
145	144	$P3_2$	146	148	$R3$
147	147	$P\bar{3}$	148	148	$R\bar{3}$
149	162	$P312$	150	164	$P321$
151	151	$P3_112$	152	152	$P3_121$
153	151	$P3_212$	154	152	$P3_221$
155	166	$R32$	156	164	$P3m1$
157	162	$P31m$	158	165	$P3c1$
159	163	$P31c$	160	166	$R3m$
161	167	$R3c$	162	162	$P\bar{3}1m$
163	163	$P\bar{3}1c$	164	164	$P\bar{3}m1$
165	165	$P\bar{3}c1$	166	166	$R\bar{3}m$
167	167	$R\bar{3}c$	168	175	$P6$
169	169	$P6_1$	170	169	$P6_5$
171	171	$P6_2$	172	171	$P6_4$

Hexagonal and Rhombohedral System (cont.)

<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>	<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>
173	176	P6 ₃	174	175	P6̄
175	175	P6/m	176	176	P6 ₃ /m
177	191	P622	178	178	P6 ₁ 22
179	178	P6 ₅ 22	180	180	P6 ₂ 22
181	180	P6 ₄ 22	182		P6 ₃ 22
183	191	P6mm	184	192	P6cc
185	193	P6 ₃ cm	186	194	P6 ₃ mc
187	191	P6̄m2	188	193	P6̄c2
189	191	P6̄2m	190	194	P6̄2c
191	191	P6/mmm	192	192	P6/mcc
193	193	P6 ₃ /mcm	194	194	P6 ₃ /mmc

Cubic System

<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>	<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>
195	200	P23	196	202	F23
197	204	I23	198		P2 ₁ 3
199	204	I2 ₁ 3	200	200	Pm3
201		Pn3	202	202	Fm3
203		Fd3	204	204	Im3
205		Pa3	206		Ia3
207	221	P432	208		P4 ₂ 32
209	225	F432	210		F4 ₁ 32
211	229	I432	212	212	P4 ₃ 32

Cubic System (cont.)

<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>	<u>Space Group No.</u>	<u>Aspect No.</u>	<u>Space Group Symbols</u>
213	212	$P4_132$	214		$I4_132$
215	221	$P\bar{4}3m$	216	225	$F\bar{4}3m$
217	229	$I\bar{4}3m$	218	223	$P\bar{4}3n$
219	226	$F\bar{4}3c$	220		$I\bar{4}3d$
221	221	$Pm3m$	222		$Pn3n$
223	223	$Pm3n$	224		$Pn3m$
225	225	$Fm3m$	226	226	$Fm3c$
227		$Fd3m$	228		$Fd3c$
229	229	$Im3m$	230		$Ia3d$

PART II

ASPECTS

Anorthic (Triclinic) System

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
$P^*, \bar{1}$	2	$P\bar{1}$ (2), $P1$ (1)

Monoclinic System

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
$P^*/^*$	10	$P2/m$ (10), $P2$ (3), Pm (6)
$P2_1/^*$	11	$P2_1/m$ (11), $P2_1$ (4)
$C^*/^*$	12A	$C2/m$ (12A), $C2$ (5A), Cm (8A)
$A^*/^*$	12B	$A2/m$ (12B), $A2$ (5B), Am (8B)
$I^*/^*$	12C	$I2/m$ (12C), $I2$ (5C), Im (8C)
P^*/c	13A	$P2/c$ (13A), Pc (7A)
P^*/a	13B	$P2/a$ (13B), Pa (7B)
P^*/n	13C	$P2/n$ (13C), Pn (7C)
C^*/c	15A	$C2/c$ (15A), Cc (9A)
A^*/a	15B	$A2/a$ (15B), Aa (9B)
I^*/a	15C	$I2/a$ (15C), Ia (9C)

Orthorhombic System

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
P^{***}	47	$Pmmm$ (47), $P222$ (16), $Pmm2$ (25A), $Pm2m$ (25B), $P2mm$ (25C)
Pcc^*	49A	$Pccm$ (49A), $Pcc2$ (27A)
P^*aa	49B	$Pmaa$ (49B), $P2aa$ (27C)
Pb^*b	49C	$Pbmb$ (49C), $Pb2b$ (27B)
$P^{**}a$	51A	$Pmma$ (51A), $P2_1ma$ (26B), $Pm2a$ (28F)
P^*c^*	51B	$Pmcm$ (51B), $Pmc2_1$ (26A), $P2cm$ (28B)

Orthorhombic System (cont.)

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
Pc**	51C	Pcmm (51C), Pcm2 ₁ (26E), Pc2m (28E)
P*a*	51D	Pmam (51D), P2 ₁ am (26C), Pma2 (28A)
Pb**	51E	Pbmm (51E), Pb2 ₁ m (26D), Pbm2 (28D)
P**b	51F	Pmmb (51F), Pm2 ₁ b (26F), P2mb (28C)
P*na	53A	Pmna (53A), P2na (30E)
Pnc*	53B	Pncm (53B), Pnc2 (30A)
Pb*n	53C	Pbm _n (53C), Pb2n (30D)
P*an	53D	Pman (53D), P2an (30F)
Pcn*	53E	Pcnm (53E), Pcn2 (30B)
Pn*b	53F	Pnmb (53F), Pn2b (30C)
Pba*	55A	Pbam (55A), Pba2 (32A)
Pc*a	55B	Pcma (55B), Pc2a (32C)
P*cb	55C	Pmcb (55C), P2cb (32B)
Pbc*	57A	Pbcm (57A), Pbc2 ₁ (29F)
Pc*b	57B	Pcmb (57B), Pc2 ₁ b (29E)
Pb*a	57C	Pbma (57C), Pb2 ₁ a (29C)
Pca*	57D	Pcam (57D), Pca2 ₁ (29A)
P*ab	57E	Pmab (57E), P2 ₁ ab (29D)
P*ca	57F	Pmca (57F), P2 ₁ ca (29B)
Pnn*	58A	Pnnm (58A), Pnn2 (34A)
Pn*n	58B	Pnm _n (58B), Pn2n (34B)
P*nn	58C	Pmnn (58C), P2nn (34C)
P**n	59A	Pmnn (59A), Pm2 ₁ n (31E), P2 ₁ mn (31F)
Pn**	59B	Pnmm (59B), Pnm2 ₁ (31B), Pn2 ₁ m (31D)

Orthorhombic System (cont.)

Aspect	Number	Space Groups (Space Group Numbers)
P*n*	59C	Pmm (59C), Pmn ₂ (31A), P ₂ ₁ nm (31C)
Pn*a	62A	Pnma (62A), Pn ₂ ₁ a (33E)
P*n _b	62B	Pmnb (62B), P ₂ ₁ nb (33D)
Pbn*	62C	Pbnm (62C), Pbn ₂ (33B)
P*cn	62D	Pmcn (62D), P ₂ ₁ cn (33C)
Pc*n	62E	Pcmn (62E), Pc ₂ ₁ n (33F)
Pna*	62F	Pnam (62F), Pna ₂ (33A)
C*c*	63A	Cmcm (63A), Cmc ₂ (36A), C ₂ cm (40B)
Bb**	63B	Bbmm (63B), Bb ₂ ₁ m (36E), Bbm ₂ (40C)
A*a*	63C	Amam (63C), A ₂ ₁ am (36B), Ama ₂ (40A)
A**a	63D	Amma (63D), A ₂ ₁ ma (36C), Am ₂ a (40F)
Cc**	63E	Ccmm (63E), Ccm ₂ (36F), Cc ₂ m (40E)
B**b	63F	Bmmb (63F), Bm ₂ ₁ b (36D), B ₂ mb (40D)
C*ca	64A	Cmca (64A), C ₂ ca (41C)
Aba*	64B	Abam (64B), Aba ₂ (41A)
Cc*a	64C	Ccma (64C), Cc ₂ a (41E)
Ab*a	64D	Abma (64D), Ab ₂ a (41B)
B*ab	64E	Bmab (64E), B ₂ ab (41D)
Bba*	64F	Bbam (64F), Bba ₂ (41F)
C***	65A	Cmmm (65A), C ₂ 22 (21A), Cmm ₂ (35A), C ₂ mm (38D), Cm ₂ m (38F)
B***	65B	Bmmm (65B), B ₂ 22 (21B), Bm ₂ m (35B), B ₂ mm (38C), Bmm ₂ (38E)
A***	65C	Ammm (65C), A ₂ 22 (21C), A ₂ mm (35C), Amm ₂ (38A), Am ₂ m (38B)
Ccc*	66A	Cccm (66A), Ccc ₂ (37A)
A*aa	66B	Amaa (66B), A ₂ aa (37B)

Orthorhombic System (cont.)

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
Bb*b	66C	Bbmb (66C), Bb2b (37C)
C**a	67A	Cmma (67A), C2ma (39C), Cm2a (39E)
Ab**	67B	Abmm (67B), Abm2 (39A), Ab2m (39D)
B*a*	67C	Bmam (67C), Bma2 (39B), B2am (39F)
F***	69	Fmmm (69), F222 (22), Fmm2 (42A), Fm2m (42B), F2mm (42C)
I***	71	Immm (71), I222 (23), $I2_12_12_1$ (24), Imm2 (44A), Im2m (44B), I2mm (44C)
Iba*	72A	Ibam (72A), Iba2 (45A)
I*aa	72B	Imaa (72B), I2aa (45C)
Ib*a	72C	Ibma (72C), Ib2a (45B)
I**a	74A	Imma (74A), Im2a (46B), I2ma (46F)
Ib**	74B	Ibmm (74B), Ib2m (46C), Ib2m (46E)
I*a*	74C	Imam (74C), Ima2 (46A), I2am (46D)

Tetragonal System

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
$P4_{1,3}$	76	$P4_1$ (76), $P4_3$ (78)
$P4/*$	83	$P4/m$ (83), $P4$ (75), $P\bar{4}$ (81)
$P4_2/*$	84	$P4_2/m$ (84), $P4_2$ (77)
$I4/*$	87	$I4/m$ (87), $I4$ (79), $I\bar{4}$ (82)
$P4_{1,3}22$	91	$P4_122$ (91), $P4_322$ (95)
$P4_{1,3}2_12$	92	$P4_12_12$ (92), $P4_32_12$ (96)
$P42_1*$	113	$P\bar{4}2_1m$ (113), $P42_12$ (90)
$I4*d$	122	$I\bar{4}2d$ (122), $I4_1md$ (109)
$P4/***$	123	$P4/mmm$ (123), $P422$ (89), $P4mm$ (99), $P\bar{4}2m$ (111), $P\bar{4}m2$ (115)

Tetragonal System (cont.)

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
P4/*cc	124	P4/mcc (124), P4cc (103)
P4/*b*	127	P4/mbm (127), P4bm (100), $P\bar{4}b2$ (117)
P4/*nc	128	P4/mnc (128), P4nc (104)
P4/**c	131	P ₄ ₂ /mmc (131), P ₄ ₂ mc (105), $P\bar{4}2c$ (112)
P4/*c*	132	P ₄ ₂ /mcm (132), P ₄ ₂ cm (101), $P\bar{4}c2$ (116)
P4/*bc	135	P ₄ ₂ /mbc (135), P ₄ ₂ bc (106)
P4/*n*	136	P ₄ ₂ /nm (136), P ₄ ₂ nm (102), $P\bar{4}n2$ (118)
I4/***	139	I4/mmm (139), I422 (97), I4mm (107), $I\bar{4}m2$ (119), $I\bar{4}2m$ (121)
I4/*c*	140	I4/mcm (140), I4cm (108), $I\bar{4}c2$ (120)

Hexagonal and Rhombohedral System

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
P ₃ _{1,2}	144	P ₃ ₁ (144), P ₃ ₂ (145)
P*, $\bar{3}$	147	$P\bar{3}$ (147), P ₃ (143)
R*	148	$R\bar{3}$ (148), R ₃ (146)
P ₃ _{1,2} 12	151	P ₃ ₁ 12 (151), P ₃ ₂ 12 (153)
P ₃ _{1,2} 21	152	P ₃ ₁ 21 (152), P ₃ ₂ 21 (154)
P31*	162	$P\bar{3}1m$ (162), P312 (149), P31m (157)
P*1c, $\bar{3}m$	163	$P\bar{3}1c$ (163), P31c (159)
P3*1	164	$P\bar{3}m1$ (164), P321 (150), P3m1 (156)
P*c1, $\bar{3}m$	165	$P\bar{3}c1$ (165), P3c1 (158)
R**	166	$R\bar{3}m$ (166), R32 (155), R3m (160)
R*c	167	$R\bar{3}c$ (167), R3c (161)
P6 _{1,5}	169	P6 ₁ (169), P6 ₅ (170)
P6 _{2,4}	171	P6 ₂ (171), P6 ₄ (172)

Hexagonal and Rhombohedral System (cont.)

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
P6/*	175	P6/m (175), P6 (168), $P\bar{6}$ (174)
P6 ₃ /*	176	P6 ₃ /m (176), P6 ₃ (173)
P6 ₁ , ₅ 22	178	P6 ₁ 22 (178), P6 ₅ 22 (179)
P6 ₂ , ₄ 22	180	P6 ₂ 22 (180), P6 ₄ 22 (181)
P6/***	191	P6/mmm (191), P622 (177), P6mm (183), $P\bar{6}m2$ (187), $P\bar{6}2m$ (189)
P6/*cc	192	P6/mcc (192), P6cc (184)
P6/*c*	193	P6 ₃ /mcm (193), P6 ₃ cm (185), $P\bar{6}c2$ (188)
P6/**c	194	P6 ₃ /mmc (194), P6 ₃ mc (186), $P\bar{6}2c$ (190)

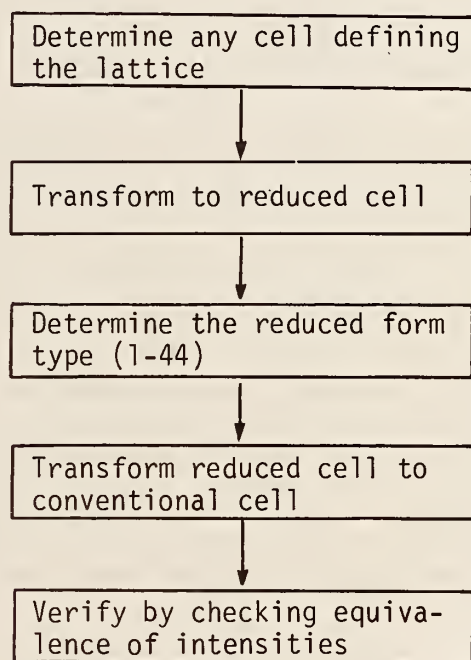
Cubic System

<u>Aspect</u>	<u>Number</u>	<u>Space Groups (Space Group Numbers)</u>
P*3	200	Pm3 (200), P23 (195)
F*3	202	Fm3 (202), F23 (196)
I*3	204	Im3 (204), I23 (197), I2 ₁ 3 (199)
P4 ₁ , ₃ 32	212	P4 ₃ 32 (212), P4 ₁ 32 (213)
P*3*	221	Pm3m (221), P432 (207), $P\bar{4}3m$ (215)
P*3n	223	Pm3n (223), $P\bar{4}3n$ (218)
F*3*	225	Fm3m (225), F432 (209), $F\bar{4}3m$ (216)
F*3c	226	Fm3c (226), $F\bar{4}3c$ (219)
I*3*	229	Im3m (229), I432 (211), $I\bar{4}3m$ (217)

APPENDIX B

LATTICE SYMMETRY DETERMINATION

There exists a close correlation between the metric symmetry (i.e. the symmetry determined from the cell parameters alone) and the crystal symmetry of the lattice. It has been shown that for 97 percent of the entries in the NBS Crystal Data File, the metric symmetry is the same as the crystal symmetry reported by the authors.⁶ Thus it was concluded that more emphasis should be placed on cell determination and refinement algorithms used in routine diffractometry because of the basic importance of the metric lattice in crystallography. A convenient procedure to determine crystal symmetry is as follows:



The algorithm used by NBS*AIDS80 to calculate the reduced cell guarantees that both the main and special conditions for reduction are satisfied.⁴ If only the main conditions for reduction are satisfied, one obtains a cell based on the shortest three non-coplanar translations. However, the special conditions must also be satisfied since in certain lattices two or more cells may be based on the shortest three translations.⁴ In fact, Gruber¹⁴ has shown that as many as five different cells of this type may exist in the same lattice. Thus the special conditions are necessary to define one and only one of these cells as the reduced cell. Table 1 gives the main and special conditions used by NBS*AIDS80 to determine the reduced cell.

Based on the reduced cell, NBS*AIDS80 calculates the vector products

defining the reduced form:

$$\begin{pmatrix} \bar{a} \cdot \bar{a} & \bar{b} \cdot \bar{b} & \bar{c} \cdot \bar{c} \\ \bar{b} \cdot \bar{c} & \bar{a} \cdot \bar{c} & \bar{a} \cdot \bar{b} \end{pmatrix}$$

From the reduced form, the reduced form type (1-44) is assigned. Table 2 gives the conditions for the 44 reduced forms, as well as the matrices relating each reduced form to a corresponding conventional cell of the Bravais lattice. This table⁶ is derived from Table 5.1.3.1 of the International Tables for X-ray Crystallography,⁵ including the published addenda and errata.^{15,16} Thus to find the metric symmetry of an unknown, one can introduce any cell of the lattice on Card 1; if the cell is not primitive, the centering must be specified on Card 3. The program calculates the reduced cell, reduced form, and reduced form type. If the metric symmetry exceeds the input crystal symmetry, both the higher symmetry cell and the transformation matrix (input cell to Crystal Data conventional cell¹) will be output. In practice we have found it convenient to determine a primitive triclinic cell on the diffractometer and use NBS*AIDS80 to suggest the lattice symmetry.

It is essential that the input cell be determined as accurately as possible. Usually the program will find the correct metric symmetry with the input of a refined cell determined from a diffractometer. However, caution should be used in the interpretation of metric symmetry. In its present form NBS*AIDS80 has the practical and theoretical limitation of determining only one metric cell when, in certain cases, more than one answer may be possible owing to experimental errors in the input cell. Thus the reduced cell and reduced form should be checked using Tables 1 and 2 to determine if an alternative symmetry might be considered. For example, the program may indicate a symmetry lower than the lattice symmetry because of inexact determination of cell angles; idealization of the experimental angles (e.g. 90°) may be necessary to obtain the correct analysis. Also, if the reduced form exhibits more specialization than is required to define the lattice type, it may signify that a subcell of the lattice has been input or that the material is twinned.

We have noted from our experience with obtaining cells from an automated diffractometer as well as from analysis of the data in the NBS Crystal Data File that the determination of a subcell of the lattice is a common source of error. A number of structure determinations have been carried out using only half of the available unique data; this error often results in apparent disorder in the refined structure. If it is suspected that a subcell of the lattice has been determined, one can obtain the cells of 2, 3, and 4 times the volume by applying the upper triangular Q matrices given in Table 3 to any primitive cell of the lattice.¹⁷ The seven cells of twice the original volume, thirteen cells of three times the volume, or 35 cells of four times the volume can be used to calculate the positions of the nodes in reciprocal space to be checked for diffraction intensity. Alternatively, one can apply the transpose of the inverse of the Q matrices to the reciprocal cell to determine the nodes.

Table 1. Conditions for a Reduced Cell^{*}

A. Positive reduced form, type I cell, all angles $< 90^\circ$

$$\text{Main conditions: } a \cdot a \leq b \cdot b \leq c \cdot c ; b \cdot c \leq \frac{1}{2} b \cdot b ; a \cdot c \leq \frac{1}{2} a \cdot a ; \\ a \cdot b \leq \frac{1}{2} a \cdot a$$

$$\begin{aligned} \text{Special conditions: (a) if } a \cdot a = b \cdot b & \quad \text{then } b \cdot c \leq a \cdot c \\ \text{(b) if } b \cdot b = c \cdot c & \quad \text{then } a \cdot c \leq a \cdot b \\ \text{(c) if } b \cdot c = \frac{1}{2} b \cdot b & \quad \text{then } a \cdot b \leq 2 a \cdot c \\ \text{(d) if } a \cdot c = \frac{1}{2} a \cdot a & \quad \text{then } a \cdot b \leq 2 b \cdot c \\ \text{(e) if } a \cdot b = \frac{1}{2} a \cdot a & \quad \text{then } a \cdot c \leq 2 b \cdot c \end{aligned}$$

B. Negative reduced form, type II cell, all angles $\geq 90^\circ$

$$\begin{aligned} \text{Main conditions: (a) } a \cdot a \leq b \cdot b \leq c \cdot c ; \quad |b \cdot c| \leq \frac{1}{2} b \cdot b ; \\ |a \cdot c| \leq \frac{1}{2} a \cdot a ; \quad |a \cdot b| \leq \frac{1}{2} a \cdot a \\ \text{(b) } (|b \cdot c| + |a \cdot c| + |a \cdot b|) \leq \frac{1}{2} (a \cdot a + b \cdot b) \end{aligned}$$

$$\begin{aligned} \text{Special conditions: (a) if } a \cdot a = b \cdot b & \quad \text{then } |b \cdot c| \leq |a \cdot c| \\ \text{(b) if } b \cdot b = c \cdot c & \quad \text{then } |a \cdot c| \leq |a \cdot b| \\ \text{(c) if } |b \cdot c| = \frac{1}{2} b \cdot b & \quad \text{then } a \cdot b = 0 \\ \text{(d) if } |a \cdot c| = \frac{1}{2} a \cdot a & \quad \text{then } a \cdot b = 0 \\ \text{(e) if } |a \cdot b| = \frac{1}{2} a \cdot a & \quad \text{then } a \cdot c = 0 \\ \text{(f) if } (|b \cdot c| + |a \cdot c| + |a \cdot b|) = \frac{1}{2} (a \cdot a + b \cdot b) & \\ \text{then } a \cdot a \leq 2 |a \cdot c| + |a \cdot b| & \end{aligned}$$

^{*}For further details see the discussion in Reference 5.

Table 2. Metric Classification of Reduced Forms*

Reduced Form No.	Reduced Form Matrix				Reduced Form Type	Bravais Lattice	Cell Transformation Reduced → Conventional
	First Row	Second Row					
		a·a b·b c·c	b·c	a·c			
a = b = c							
1	a·a a·a a·a	$\frac{a \cdot a}{2}$	$\frac{a \cdot a}{2}$	$\frac{a \cdot a}{2}$	+	Cubic F	$\bar{1}\bar{1}\bar{1}/\bar{1}\bar{1}\bar{1}/\bar{1}\bar{1}\bar{1}$
2	a·a a·a a·a	b·c	b·c	b·c	+	Rhombohedral hR	$\bar{1}\bar{1}\bar{0}/\bar{1}\bar{0}\bar{1}/\bar{1}\bar{1}\bar{1}$
3	a·a a·a a·a	0	0	0	-	Cubic P	100/010/001
4	a·a a·a a·a	- b·c	- b·c	- b·c	-	Rhombohedral hR	$\bar{1}\bar{1}\bar{0}/\bar{1}\bar{0}\bar{1}/\bar{1}\bar{1}\bar{1}$
5	a·a a·a a·a	$-\frac{a \cdot a}{3}$	$-\frac{a \cdot a}{3}$	$-\frac{a \cdot a}{3}$	-	Cubic I	101/110/011
6	a·a a·a a·a	$\frac{-a \cdot a + a \cdot b }{2}$	$\frac{-a \cdot a + a \cdot b }{2}$	- a·b	-	Tetragonal I	011/101/110
7	a·a a·a a·a	- b·c	$\frac{-a \cdot a + b \cdot c }{2}$	$\frac{-a \cdot a + b \cdot c }{2}$	-	Tetragonal I	101/110/011
8	a·a a·a a·a	- b·c	- a·c	$-(a \cdot a - b \cdot c - a \cdot c)$	-	Orthorhombic I	$\bar{1}\bar{1}\bar{0}/\bar{1}\bar{0}\bar{1}/\bar{0}\bar{1}\bar{1}$
a = b							
9	a·a a·a c·c	$\frac{a \cdot a}{2}$	$\frac{a \cdot a}{2}$	$\frac{a \cdot a}{2}$	+	Rhombohedral hR	$100/\bar{1}\bar{1}\bar{0}/\bar{1}\bar{1}\bar{3}$
10	a·a a·a c·c	b·c	b·c	a·b	+	Monoclinic C**	$110/\bar{1}\bar{1}\bar{0}/00\bar{1}$
11	a·a a·a c·c	0	0	0	-	Tetragonal P	100/010/001
12	a·a a·a c·c	0	0	$-\frac{a \cdot a}{2}$	-	Hexagonal P	100/010/001
13	a·a a·a c·c	0	0	- a·b	-	Orthorhombic C	$110/\bar{1}\bar{1}\bar{0}/001$
14	a·a a·a c·c	- b·c	- b·c	- a·b	-	Monoclinic C**	$110/\bar{1}\bar{1}\bar{0}/001$
15	a·a a·a c·c	$-\frac{a \cdot a}{2}$	$-\frac{a \cdot a}{2}$	0	-	Tetragonal I	100/010/112
16	a·a a·a c·c	- b·c	- b·c	$-(a \cdot a - 2 b \cdot c)$	-	Orthorhombic F	$\bar{1}\bar{1}\bar{0}/\bar{1}\bar{1}\bar{0}/112$
17	a·a a·a c·c	- b·c	- a·c	$-(a \cdot a - b \cdot c - a \cdot c)$	-	Monoclinic I††	$\bar{1}\bar{0}\bar{1}/\bar{1}\bar{1}\bar{0}/011$
b = c							
18	a·a b·b b·b	$\frac{a \cdot a}{4}$	$\frac{a \cdot a}{2}$	$\frac{a \cdot a}{2}$	+	Tetragonal I	$0\bar{1}\bar{1}/\bar{1}\bar{1}\bar{1}/100$
19	a·a b·b b·b	b·c	$\frac{a \cdot a}{2}$	$\frac{a \cdot a}{2}$	+	Orthorhombic I	$\bar{1}\bar{0}\bar{0}/0\bar{1}\bar{1}/\bar{1}\bar{1}\bar{1}$
20	a·a b·b b·b	b·c	a·c	a·c	+	Monoclinic C†	$011/0\bar{1}\bar{1}/\bar{1}\bar{0}\bar{0}$
21	a·a b·b b·b	0	0	0	-	Tetragonal P	010/001/100
22	a·a b·b b·b	$-\frac{b \cdot b}{2}$	0	0	-	Hexagonal P	010/001/100
23	a·a b·b b·b	- b·c	0	0	-	Orthorhombic C	$011/0\bar{1}\bar{1}/100$
24	a·a b·b b·b	$\frac{b \cdot b - \frac{a \cdot a}{3}}{2}$	$-\frac{a \cdot a}{3}$	$-\frac{a \cdot a}{3}$	-	Rhombohedral hR	$121/0\bar{1}\bar{1}/100$
25	a·a b·b b·b	- b·c	- a·c	- a·c	-	Monoclinic C†	$011/0\bar{1}\bar{1}/100$

Table 2. (continued)

Reduced Form No.	Reduced Form Matrix				Reduced Form Type	Bravais Lattice	Cell Transformation Reduced → Conventional
	First Row†††	Second Row					
		a·a b·b c·c	b·c	a·c			
a ≤ b ≤ c 26	a·a b·b c·c	$\frac{a·a}{4}$	$\frac{a·a}{2}$	$\frac{a·a}{2}$	+	Orthorhombic F	100/ $\bar{1}20$ / $\bar{1}02$
27	a·a b·b c·c	b·c	$\frac{a·a}{2}$	$\frac{a·a}{2}$	+	Monoclinic I***	0 $\bar{1}1$ / $\bar{1}00$ / $\bar{1}\bar{1}$
28	a·a b·b c·c	$\frac{a·b}{2}$	$\frac{a·a}{2}$	a·b	+	Monoclinic C	$\bar{1}00$ / $\bar{1}02$ /010
29	a·a b·b c·c	$\frac{a·c}{2}$	a·c	$\frac{a·a}{2}$	+	Monoclinic C	100/ $\bar{1}20$ /00 $\bar{1}$
30	a·a b·b c·c	$\frac{b·b}{2}$	$\frac{a·b}{2}$	a·b	+	Monoclinic C	010/01 $\bar{2}$ / $\bar{1}00$
31	a·a b·b c·c	b·c	a·c	a·b	+	Triclinic P	100/010/001
32	a·a b·b c·c	0	0	0	-	Orthorhombic P	100/010/001
33	a·a b·b c·c	0	- a·c	0	-	Monoclinic P	100/010/001
34	a·a b·b c·c	0	0	- a·b	-	Monoclinic P	$\bar{1}00$ /00 $\bar{1}$ /0 $\bar{1}0$
35	a·a b·b c·c	- b·c	0	0	-	Monoclinic P	0 $\bar{1}0$ / $\bar{1}00$ /00 $\bar{1}$
36	a·a b·b c·c	0	$-\frac{a·a}{2}$	0	-	Orthorhombic C	100/ $\bar{1}0\bar{2}$ /010
37	a·a b·b c·c	- b·c	$-\frac{a·a}{2}$	0	-	Monoclinic C*	102/100/010
38	a·a b·b c·c	0	0	$-\frac{a·a}{2}$	-	Orthorhombic C	$\bar{1}00$ /120/00 $\bar{1}$
39	a·a b·b c·c	- b·c	0	$-\frac{a·a}{2}$	-	Monoclinic C**	$\bar{1}\bar{2}0$ / $\bar{1}00$ /00 $\bar{1}$
40	a·a b·b c·c	$-\frac{b·b}{2}$	0	0	-	Orthorhombic C	0 $\bar{1}0$ /012/ $\bar{1}00$
41	a·a b·b c·c	$-\frac{b·b}{2}$	- a·c	0	-	Monoclinic C†	0 $\bar{1}\bar{2}$ /0 $\bar{1}0$ / $\bar{1}00$
42	a·a b·b c·c	$-\frac{b·b}{2}$	$-\frac{a·a}{2}$	0	-	Orthorhombic I	$\bar{1}00$ /0 $\bar{1}0$ /112
43	a·a b·b c·c	$-\frac{b·b - a·b }{2}$	$-\frac{a·a - a·b }{2}$	- a·b	-	Monoclinic I	$\bar{1}00$ / $\bar{1}\bar{1}\bar{2}$ /0 $\bar{1}0$
44	a·a b·b c·c	- b·c	- a·c	- a·b	-	Triclinic P	100/010/001

† If $a·a < 4|a·c|$ }
 * If $b·b < 4|b·c|$ } Premultiply Table Matrix by 00 $\bar{1}$ /010/101 (I centered)
 ** If $c·c < 4|b·c|$ }

†† If $3a·a < c·c + 2|a·c|$ }
 *** If $3b·b < c·c + 2|b·c|$ } Premultiply Table Matrix by $\bar{1}0\bar{1}$ /010/100 (C centered)

††† No required relationships between symmetrical scalars for reduced forms 26-44.

* Reprinted from Reference 6. Based on Table 5.1.3.1 prepared by A. Mighell, A. Santoro, and J. D. H. Donnay for the International Tables for X-ray Crystallography⁵ and published revisions.^{15,16}

Table 3. Unique \mathcal{Q} Matrices Generating Superlattices for $|\mathcal{Q}| = 2, 3, 4^*$

$ \mathcal{Q} = 2$	$ \mathcal{Q} = 4$	$ \mathcal{Q} = 4$
100/010/002	100/010/004	111/020/002
100/011/002	100/011/004	111/021/002
101/010/002	100/012/004	100/040/001
101/011/002	100/013/004	110/040/001
100/020/001	101/010/004	120/040/001
110/020/001	101/011/004	130/040/001
200/010/001	101/012/004	200/010/002
	101/013/004	200/011/002
$ \mathcal{Q} = 3$	102/010/004	201/010/002
100/010/003	102/011/004	201/011/002
100/011/003	102/012/004	200/020/001
100/012/003	102/013/004	210/020/001
101/010/003	103/010/004	400/010/001
101/011/003	103/011/004	
101/012/003	103/012/004	
102/010/003	103/013/004	
102/011/003	100/020/002	
102/012/003	100/021/002	
100/030/001	101/020/002	
110/030/001	101/021/002	
120/030/001	110/020/002	
300/010/001	110/021/002	

* For each value of $|\mathcal{Q}|$ the matrices can be applied to any primitive cell of the original lattice, but they must be applied to the same cell.

APPENDIX C

EXAMPLES OF INPUT DECKS AND OUTPUT LISTINGS

Example 1. Cell analysis for two data sets

Input deck:

1	0			0		1	
2	12.83	9.026	13.44		123.0		TEST01M1
3	.02	.009	.05		.5		2
4	CC		4	1.46			3
5	Sodium carbonate decahydrate						6
6	NA2 C O3 110 H2 O						7
7	Example of cell analysis and density calculation						8
8							K
9	8.095	8.096	30.62	88.67	58.08	87.48	TEST02A1
10	P						3
11	Example of symmetry determination						B
12							K

Output listing:

*** MCNOCLINIC ***** TEST01 ***														
1	1	1	2	1	3	1	4	1	5	1	6	1	7	
12.83	9.026	13.44				123.0								CELL
.02	.009	.05				.5								ESDS
Cc	9A	4	1.460								209	C-		SG-1
Cc	9A	4		1.456						286.14		1305.31		SG-2
Sodium carbonate decahydrate														NAME
Na2 C O3 110 H2 O														CHEM
C H2O Na2 C13														EMPR
Example of cell analysis and density calculation														COMM
T-2	.50	.50	.00 /	-.50	.50	.00 /	.50	-.50	1.00					MATX
1.00:	1.00	.00	.00 /	.00	-1.00	.00 /	-1.00	.00	-1.00					MATX
INV	1.00	.00	.00 /	.00	-1.00	.00 /	-1.00	.00	-1.00					MATX
12.830	9.026	13.440	90.00	123.00	90.00	1305.31								C-IN
7.843	7.843	12.175	98.77	105.91	109.75	652.65								C-RD
12.830	9.026	12.546	90.00	116.05	90.00	1.4214	1.3900							C-CD
.020	.009	.104	.00	.35	.00									E-CD
61.519	61.519	148.238	-14.562	-26.172	-20.785									DOTM
01/12/81 0 0 45 16/12/80														HIST

*** ANORTHIC ***** TEST02 ***														
WARNINGAI,BI AND/OR CI > 30A														
WARNINGMETRIC SYMMETRY EXCEEDS CRYSTAL SYMMETRY														
CRYSTAL DATA BRAVAIS LATTICE = AP BRAVAIS LATTICE FROM REDUCED CELL=OB														
OB CELL PARAMETERS: 11.698 25.990 11.194 90.00 90.01 90.00														
MATRIX (INITIAL TO OB): -1.0-1.0 .0/-2.0 .0 1.0/-1.0 1.0 .0														
1	1	1	2	1	3	1	4	1	5	1	6	1	7	
8.095	8.096	30.62	88.67	58.08	87.48									CELL
														95E C
P	0											1701.65		ESDS
P	0											1701.65		SG-1
Example of symmetry determination														SG-2
T-2	.00	1.00	.00 /	-1.00	.00	.00 /	-2.00	.00	1.00					COMM
1.00:	-1.00	.00	.00 /	-2.00	.00	1.00 /	.00	1.00	.00					MATX
INV	-1.00	.00	.00 /	.00	.00	1.00 /	-2.00	1.00	.00					MATX
8.095	8.096	30.620	88.67	58.08	87.48	1701.65								C-IN
8.096	8.095	25.990	90.00	90.00	92.52	1701.65								C-RD
8.095	25.990	8.096	90.00	92.52	90.00	.3115	.3115							C-CD
65.545	65.529	675.473	.001	-.009	-2.882									DOTM
01/12/81 2 0 45 16/12/80														HIST

Example 2. Generation of d-spacings and hkl indices

Input deck:

1	2	0	40	1	
2	12.214				TEST03C1
3	PA3	4	1.670		3
4	SODIUM ALUMINUM SULFATE HYDRATE (SODA ALUM)				6
5	NA AL (S O4)2 112 H2 O				7
6	Example of hkl/d-generation				8
7	1.540598				F
8					K

Output listing:

*** CUBIC ***** TEST03 ***														
1	1	1	2	1	3	1	4	1	5	1	6	1	7	
12.214														CELL
											40E B-			ESDS
Pa3	205		4				1.670					1822.11		SG-1
Pa3	205		4				1.671			458.27		1822.11		SG-2
SODIUM ALLMINUM SULFATE HYDRATE (SCDA ALUM)														NAME
Na AL (S C4)2 112 H2 O														CHEM
AL H24 Na C20 S2														EMPR
Example of hkl/d-generation														COMM
T-2	1.00	.00	.00 /	.00	1.00	.00 /	.00	.00	1.00					MATX
1.00:	1.00	.00	.00 /	.00	1.00	.00 /	.00	.00	1.00					MATX
12.214	12.214	12.214	90.00	90.00	90.00	90.00	1822.11							C-IN
12.214	12.214	12.214	90.00	90.00	90.00	90.00	1822.11						3	C-RD
12.214	12.214	12.214	90.00	90.00	90.00	90.00	12.2140							C-CD
149.182	149.182	149.182	.0000	.0000	.0000									DOTM
1.540598														PDF1
01/12/81 0 0 45 16/12/80														HIST

MESSAGEPCWDER PATTERN GENERATION/ANALYSIS FOR SYSTEM CUB

2-THETA(MAX)= 40.00 D(MIN)= 2.252212

3 CONDITIONS FOR NON-EXTINCTION CALLED FOR

CLASS CONDITION(S)

CKL K =2N

HOL L =2N

HKO H =2N

N	D CALC	D OBS	INT	<AUTHORS>			<PROGRAM>			OBS 2-THETA	CALC 2-THETA	DIFF 2-THETA
				H	K	L	H	K	L			
1	7.0518						1	1	1		12.542	
2	6.1070						0	2	0		14.492	
3	5.4623						2	1	0		16.214	
4	4.5863						1	2	1		17.773	
5	4.3183						2	2	0		20.551	
6	4.0713						2	2	1		21.812	
7	3.6827						1	3	1		24.147	
8	3.5259						2	2	2		25.238	
9	3.3876						2	3	0		26.287	
10	3.2643						2	3	1		27.298	
11	3.0535						0	4	0		29.223	
12	2.9623						2	3	2		30.144	
13	2.8789						1	4	1		31.039	
14	2.8021						3	3	1		31.912	
15	2.7311						2	4	0		32.764	
16	2.6653						2	4	1		33.597	
17	2.6040						3	3	2		34.412	
18	2.4932						2	4	2		35.994	
19	2.4428						4	3	0		36.762	
20	2.3954						3	4	1		37.517	
21	2.3506						1	5	1		38.259	
22	2.2681						2	5	0		39.708	

Example 3. Powder pattern analysis with calculation of figures of merit

Input deck:

```
1      0      1      1
2      8.8659      5.0433      TEST04H1
3      .0006      .0005
4      P321      3      2.729
5      Sodium Silicon Fluoride
6      Na2 Si F6
7      Example of powder pattern analysis including calc of figures of merit
8      1.540598      2
9      17.58      13      0      0      1      20.03      100      1      1      0      21.07      95      1      0      1      1
10     26.74      90      1      1      1      29.20      50      2      0      1      30.79      9      2      1      0      2
11     35.05      5      3      0      0      35.58      7      0      0      2      35.66      15      2      1      1      3
12     37.54      1      1      0      2      39.47      90      3      0      1      40.68      6      2      2      0      4
13     41.16      4      1      1      2      42.42      3      3      1      0      42.88      4      2      0      2      5
14     44.61      9      2      2      1      46.22      6      3      1      1      47.72      10      2      1      2      6
15     50.79      55      3      0      2      51.86      4      3      2      0      54.56      2      0      0      3      7
16     55.19      20      3      2      1      55.96      4      1      0      3      56.52      9      3      1      2      8
17     57.94      20      4      1      1      58.69      4      1      1      3      60.01      3      2      0      3      9
18     60.60      3      4      0      2      62.84      11      3      3      0      63.23      5      5      0      1      10
19     63.94      8      2      1      3      64.11      8      4      2      0      66.50      3      3      0      3      11
20     67.03      8      4      1      2      67.03      8      4      2      1
21
```

Output listing:

```
*** HEXAGCNAL ***** TEST04 ***
1      1      1      2      1      3      1      4      1      5      1      6      1      7
8.8659      5.0433
.0006      .0005
P321      150      3      2.729      343.31
P321      150      3      2.729      188.06      343.31
Sodium Silicon Fluoride
Na2 Si F6
F6 Na2 Si
Example of powder pattern analysis including calc of figures of merit
T-2      .00      .00      1.00 / 1.00      .00      .00 / .00      1.00      .00
1.00: 1.00      .00      .00 / .00      1.00      .00 / .00      .00      1.00
8.866      8.866      5.043      90.00      90.00      120.00      343.31
5.043      8.866      8.866      120.00      90.00      90.00      343.31      22
8.866      8.866      5.043      90.00      90.00      120.00      .5688
.001      .001      .000      .00      .00      .00
25.435      78.604      78.604      -39.302      .000      .000
1.540598
01/12/81 0 0 45 16/12/80
CELL
ESDS
SG-1
SG-2
NAME
CHEM
EMPR
COMM
MATX
MATX
C-IN
C-RD
C-CD
E-CD
DGTM
PDF1
HIST

***MESSAGE**PCWDER PATTERN GENERATION/ANALYSIS FOR SYSTEM HEX

2-THETA(MAX)= 68.03      D(MIN)= 1.376990

0 CONDITIONS FOR NON-EXTINCTION CALLED FOR
CLASS CONDITION(S)

<AUTHORS>      <PROGRAM>      OBS      CALC      DIFF
N      D CALC      D OBS      INT      H      K      L      H      K      L      2-THETA      2-THETA      2-THETA
1      7.6781
2      5.0433
***      5.0433      5.0408      13      0      0      1      17.580      17.571      -.009
3      4.4329
***      4.4329      4.4294      100      1      1      0      20.030      20.014      -.016
4      4.2153
***      4.2153      4.2131      95      1      0      1      21.070      21.059      -.011
5      3.8250
6      3.3256
***      3.3296      3.3312      90      1      1      1      26.740      26.753      .013
7      3.0547
***      3.0547      3.0559      50      2      0      1      29.200      29.212      .012
8      2.9020
***      2.9020      2.9016      9      2      1      0      30.790      30.785      -.005
```

9	2.5594						3	0	0		35.032	
***	2.5594	2.5581	5	3	0	0				35.050	35.032	-.018
10	2.5216						0	0	2		35.573	
***	2.5216	2.5212	7	0	0	2				35.580	35.573	-.007
11	2.5153						2	1	1		35.666	
***	2.5153	2.5157	15	2	1	1				35.660	35.666	.006
12	2.3958						1	0	2		37.511	
***	2.3958	2.3939	1	1	0	2				37.540	37.511	-.029
13	2.2823						3	0	1		39.451	
***	2.2823	2.2812	90	3	0	1				39.470	39.451	-.019
14	2.2165						2	2	0		40.673	
***	2.2165	2.2161	6	2	2	0				40.680	40.673	-.007
15	2.1918						1	1	2		41.151	
***	2.1918	2.1914	4	1	1	2				41.160	41.151	-.009
.												
.												
.												
.												
.												
.												
.												
32	1.5719						1	1	3		58.688	
***	1.5719	1.5718	4	1	1	3				58.690	58.688	-.002
33	1.5399						2	0	3		60.029	
***	1.5399	1.5404	3	2	0	3				60.010	60.029	.019
34	1.5356						5	0	0		60.215	
35	1.5274						4	0	2		60.574	
***	1.5274	1.5268	3	4	0	2				60.600	60.574	-.026
36	1.4777						3	3	0		62.839	
***	1.4777	1.4776	11	3	3	0				62.840	62.839	-.001
37	1.4690						5	0	1		63.250	
***	1.4690	1.4695	5	5	0	1				63.230	63.250	.020
38	1.4547						2	1	3		63.949	
***	1.4547	1.4548	8	2	1	3				63.940	63.949	.009
39	1.4510						4	2	0		64.128	
***	1.4510	1.4514	8	4	2	0				64.110	64.128	.018
40	1.4440						3	2	2		64.475	
41	1.4180						3	3	1		65.806	
42	1.4051						3	0	3		66.490	
***	1.4051	1.4049	3	3	0	3				66.500	66.490	-.010
43	1.3955						4	1	2		67.005	
***	1.3955	1.3951	8	4	1	2				67.030	67.005	-.025
***	1.3945	1.3951	8	4	2	1				67.030	67.064	.034
44	1.3945						4	2	1		67.064	
45	1.3790						5	1	0		67.916	

REFLECTION SUMMARY FOR ENTIRE PATTERN:
ESTIMATED RESOLUTION= .075 DEG. 2-THETA

THEORETICAL LINES TOTAL= 45
THEORETICAL RESOLVABLE= 42
UNIQUE OBSERVED LINES= 34

TOTAL LINES INPUT= 35
NUMBER INDEXED= 35
NUMBER UNINDEXED= 0

*****FOR INDEXED LINES*****

AVERAGE ABS(DEL 2-THETA)= .013
LARGEST 2-THETA DIFFERENCE= .034
WITH DIFF>0.05 (STAR LIMIT)= 0
WITH DIFF>0.20 (I LIMIT)= 0

AVERAGE 2-THETA DIFFERENCE= -.001
WITH DIFF > +0.02(2-THETA)= 3
WITH DIFF < -0.02(2-THETA)= 3

M(20) = 67.17 (DLIMIT = 1.7584, # POSSIBLE = 24)

F(30) = 70.27 (DELTA 2 THETA = .0115, # POSSIBLE = 37)

U.S. DEPT. OF COMM. BIBLIOGRAPHIC DATA SHEET (See instructions)		1. PUBLICATION OR REPORT NO. NBS Tech. Note 1141	2. Performing Organ. Report No.	3. Publication Date April 1981
4. TITLE AND SUBTITLE NBS*AIDS80: A FORTRAN Program for Crystallographic Data Evaluation				
5. AUTHOR(S) A.D. Mighell, C.R. Hubbard, and J.K. Stalick				
6. PERFORMING ORGANIZATION (If joint or other than NBS, see instructions) NATIONAL BUREAU OF STANDARDS DEPARTMENT OF COMMERCE WASHINGTON, D.C. 20234			7. Contract/Grant No.	8. Type of Report & Period Covered Final
9. SPONSORING ORGANIZATION NAME AND COMPLETE ADDRESS (Street, City, State, ZIP) Same as No. 6				
10. SUPPLEMENTARY NOTES <input type="checkbox"/> Document describes a computer program; SF-185, FIPS Software Summary, is attached.				
11. ABSTRACT (A 200-word or less factual summary of most significant information. If document includes a significant bibliography or literature survey, mention it here) Techniques for the computer-assisted evaluation of crystallographic data have been developed to improve the data compilations of the NBS Crystal Data Center and the JCPDS--International Centre for Diffraction Data. The resulting computer program, NBS*AIDS80, can be used for the analysis of unit-cell and powder diffraction data by the general scientific community as well. Research and analysis components include calculation of standard cells and space groups, determination of metric symmetry, checking the data for consistency, generation of d-spacings and indices, and analysis of powder patterns with calculation of figures of merit. Detailed input and output specifications are given.				
12. KEY WORDS (Six to twelve entries; alphabetical order; capitalize only proper names; and separate key words by semicolons) Computer evaluation; crystallographic data analysis; JCPDS--International Centre for Diffraction Data; metric symmetry; NBS Crystal Data Center; powder diffraction; unit cell.				
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